EE-202 Electronics Chapter 5: Bipolar Junction Transistors Common Base Configuration

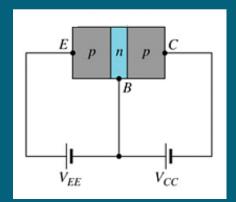
Transistor Construction

Two types of transistors:

- pnp
- npn

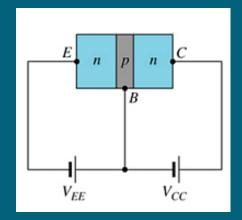
The terminals are:

- E Emitter
- B Base
- C Collector



npn

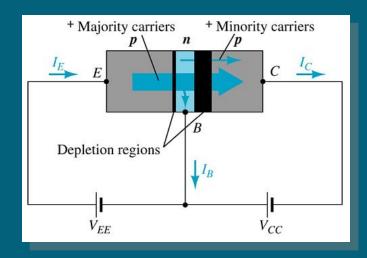
pnp



Transistor Operation

For pnp transistor, External sources, V_{EE} and V_{CC} , are connected as:

- The E-B junction is forward biased
- The B-C junction is reverse biased

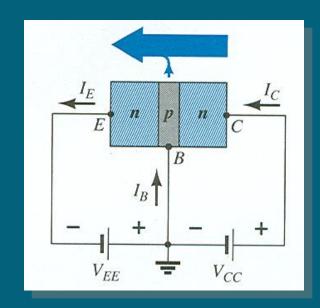


Currents in a Transistor

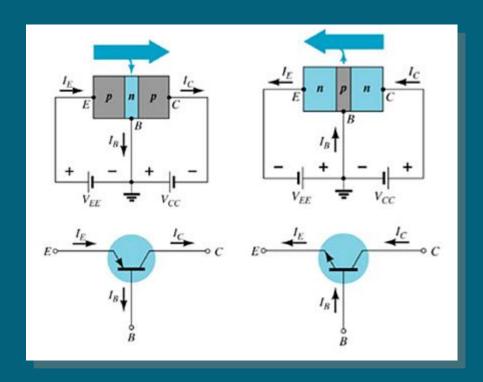
For npn transistor, Emitter current is:

$$I_E = I_C + I_B$$

The collector current is:



Common-Base Configuration

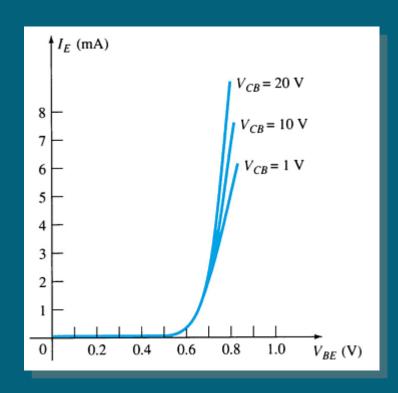


The base is common for input (E-B) and output (C-B).

Common-Base Amplifier

Input Characteristics

This curve shows the relationship between the input current (I_E) and input voltage (V_{BE}) for different levels of output voltage (V_{CB}) .



Common-Base Amplifier

Output Characteristics

The relationship between output current $(I_{C)}$ and output voltage $(V_{CB)}$ for various levels of input current (I_{E}) .

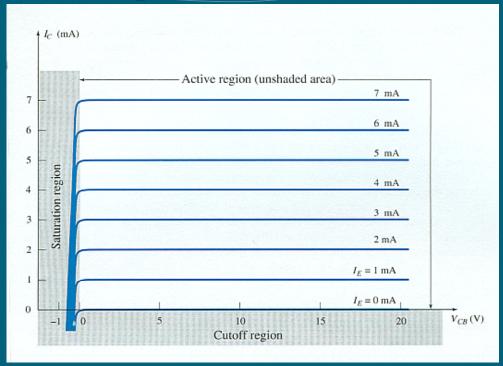
Operating Regions

Active—Operating range of the amplifier.

Cutoff—Transistor off. There is voltage, but little current.

Saturation—Transistor fully on.

There is current, but little voltage.



Approximations

Emitter and collector currents:

$$I_C \cong I_E$$

Base-emitter voltage:

$$V_{BE} = 0.7$$